



IRG8CH137K10F Information

Heisener.com

Part Number IRG8CH137K10F Manufacturer Infineon Technologies

Category Discrete Semiconductor Products

Transistors - IGBTs - Single

Description IGBT CHIP WAFER

Package Die

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com For Reference Only

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IRG8CH137K10F Specifications

Manufacturer Part Number	IRG8CH137K10F
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	Die
Series	-
IGBT Type	-
Voltage - Collector Emitter Breakdown (Max)	1200V
Current - Collector (Ic) (Max)	150A
Current - Collector Pulsed (Icm)	-
Vce(on) (Max) @ Vge, Ic	2V @ 15V, 150A
Power - Max	-
Switching Energy	-
Input Type	Standard
Gate Charge	820nC
Td (on/off) @ 25°C	115ns/570ns
Test Condition	600V, 150A, 2 Ohm, 15V
Reverse Recovery Time (trr)	-
Operating Temperature	-40°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Package / Case	Die
Supplier Device Package	Die
	Report errors?

IRG8CH137K10F Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IRG8CH137K10F Payment Methods





















IRG8CH137K10F Shipping Methods













If you have any question about IRG8CH137K10F, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com